NSN 5961-00-198-6881

Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.425 inches
Mounting Facility Quantity:
1
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
Between 0.427 inches and 0.437 inches
Thread Size:
0.190 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
50.0 working peak reverse voltage, peak total value, gate terminal open-circuited
Current Rating Per Characteristic:
300.00 amperes source cutoff current absolute
Power Rating Per Characteristic:
20.0 watts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
105.0 degrees celsius junction
Thread Series Designator:
Unf
Terminal Type And Quantity:
2 tab, solder lug and 1 threaded stud
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A110a0